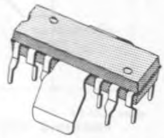
8W AUDIO AMPLIFIER

The TDA1908 is a monolithic integrated circuit in 12 lead quad in-line plastic package intended for low frequency power applications. The mounting is compatible with the old types TBA800, TBA810S, TCA830S and TCA940N. Its main features are:

- flexibility in use with a max output curent of 3A and an operating supply voltage range of 4V to 30V;
- protection against chip overtemperature;
- soft limiting in saturation conditions;
- low "switch-on" noise;
- low number of external components;
- high supply voltage rejection;
- very low noise.



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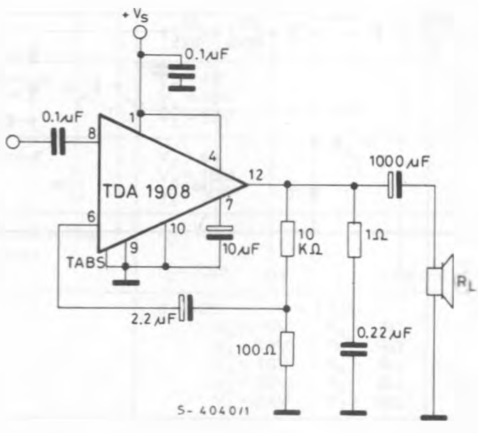
ORDER CODE: TDA1908

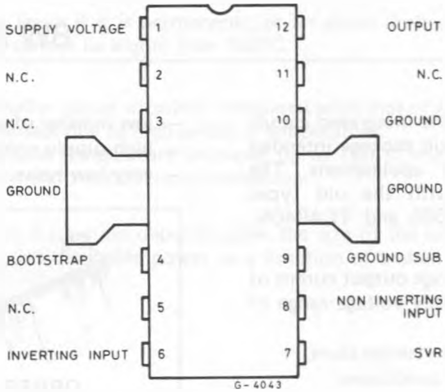
ABSOLUTE MAXIMUM RATINGS

V_s	Supply voltage	30	V
I_o	Output peak current (non repetitive)	3.5	A
I_o	Output peak current (repetitive)	3	A
P_{tot}	Power dissipation: at $T_{amb} = 80°C$	1	W
	at $T_{amb} = 90°C$	5	W
T_{stg}, T_j	Storage and junction temperature	-40 to 150	°C

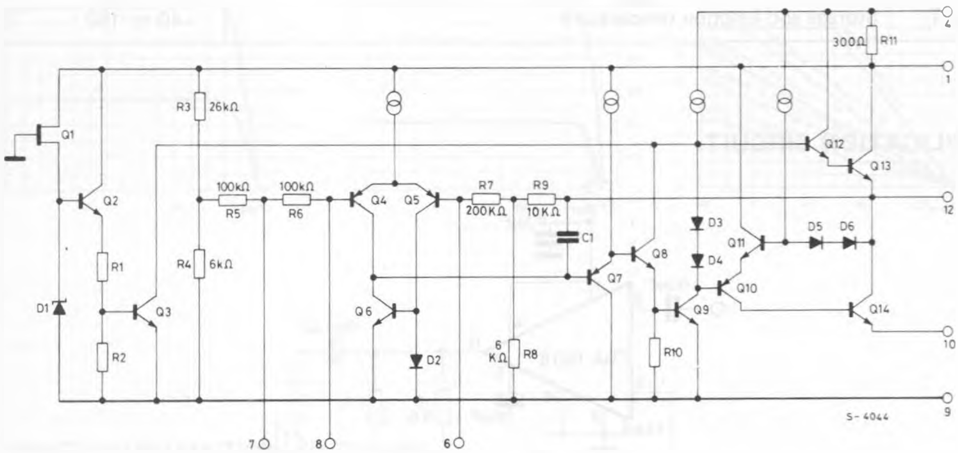
APPLICATION CIRCUIT



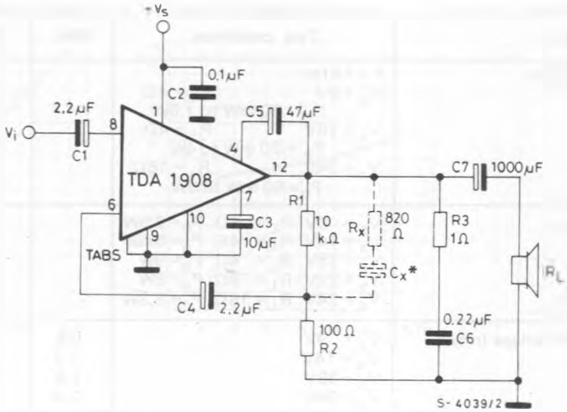
CONNECTION DIAGRAM
(top view)



SCHEMATIC DIAGRAM



TEST CIRCUIT



* See fig. 12.

THERMAL DATA

$R_{th\ j\text{-}tab}$	Thermal resistance junction-tab	max	12	°C/W
$R_{th\ j\text{-}amb}$	Thermal resistance junction-ambient	max	(°) 70	°C/W

(°) Obtained with tabs soldered to printed circuit board with min copper area.

ELECTRICAL CHARACTERISTICS (Refer to the test circuit, T_{amb}= 25°C, R_{th} (heatsink)= 8 °C/W, unless otherwise specified)

	Parameter	Test condition	Min.	Typ.	Max.	Unit
V_s	Supply voltage		4		30	V
V_o	Quiescent output voltage	V_s = 4V V_s = 18V V_s = 30V	1.6 8.2 14.4	2.1 9.2 15.5	2.5 10.2 16.8	V
I_d	Quiescent drain current	V_s = 4V V_s = 18V V_s = 30V		15 17.5 21	 35	mA
V_{CEsat}	Output stage saturation voltage (each output transistor)	I_C= 1A I_C= 2.5A		0.5 1.3		V
P_o	Output power	d = 10% f = 1 KHz V_s = 9V R_L= 4Ω V_s = 14V R_L= 4Ω V_s = 18V R_L= 4Ω V_s = 22V R_L= 8Ω V_s = 24V R_L= 16Ω	 7 6.5 4.5	 2.5 5.5 9 8 5.3		W

ELECTRICAL CHARACTERISTICS (continued)

	Parameter	Test condition	Min.	Typ.	Max	Unit
d	Harmonic distortion	f = 1KHz V_s = 9V R_L = 4Ω P_o = 50 mW to 1.5W V_s = 18V R_L = 4Ω P_o = 50 mW to 4W V_s = 24V R_L = 16Ω P_o = 50 mW to 3W		0.1 0.1 0.1		%
V_I	Input sensitivity	V_s = 9V R_L = 4Ω P_o = 2.5W V_s = 14V R_L = 4Ω P_o = 5.5W V_s = 18V R_L = 4Ω P_o = 9W V_s = 22V R_L = 8Ω P_o = 8W V_s = 24V R_L = 16Ω P_o = 5.3W		37 52 64 90 110		mV
V_I	Input saturation voltage (rms)	V_s = 9V V_s = 14V V_s = 18V V_s = 24V	0.8 1.3 1.8 2.4			V
R_I	Input resistance (pin 8)	f = 1 KHz	60	100		KΩ
I_s	Drain current	f = 1 KHz V_s = 14V R_L = 4Ω P_o = 5.5W V_s = 18V R_L = 4Ω P_o = 9W V_s = 22V R_L = 8Ω P_o = 8W V_s = 24V R_L = 16Ω P_o = 5.3W		570 730 500 310		mA
η	Efficiency	V_s = 18V f = 1 KHz R_L = 4Ω P_o = 9W		72		%
BW	Small signal bandwidth (-3 dB)	V_s = 18V R_L = 4Ω P_o = 1W	40 to 40 000			Hz
G_v	Voltage gain (open loop)	f = 1 KHz		75		dB
G_v	Voltage gain (closed loop)	V_s = 18V R_L = 4Ω f = 1 KHz P_o = 1W	39.5	40	40.5	dB
e_N	Total input noise	(°) R_g = 50Ω R_g = 1KΩ R_g = 10 KΩ		1.2 1.3 1.5	4.0	µV
		(°°) R_g = 50Ω R_g = 1KΩ R_g = 10KΩ		2.0 2.0 2.2	6.0	µV
S/N	Signal to noise ratio	V_s = 18V P_o = 9W R_L = 4Ω; R_g = 10KΩ R_g = 0 (°)		92 94		dB
		R_g = 10KΩ R_g = 0 (°°)		88 90		dB
SVR	Supply voltage rejection	V_s = 18V R_L = 4Ω f_{ripple} = 100 Hz R_g = 10KΩ	40	50		dB
T_{sd}	Thermal shut-down junction temperature (*)			145		°C

Note:
(°) Weighting filter = curve A.
(°°) Filter with noise bandwidth: 22 Hz to 22 KHz.

Fig. 1 - Quiescent output voltage vs. supply voltage

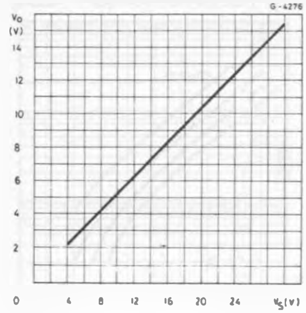


Fig. 2 - Quiescent drain current vs. supply voltage

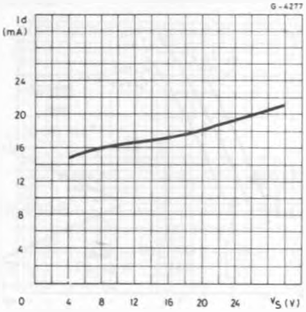


Fig. 3 - Output power vs. supply voltage

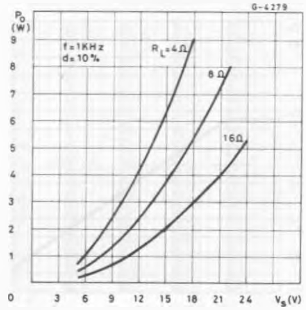


Fig. 4 - Distortion vs. output power ($R_L = 16\Omega$)

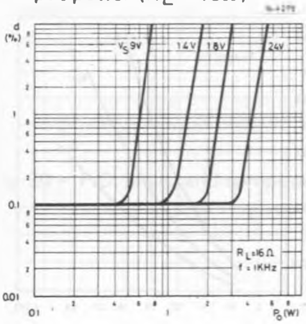


Fig. 5 - Distortion vs. output power ($R_L = 8\Omega$)

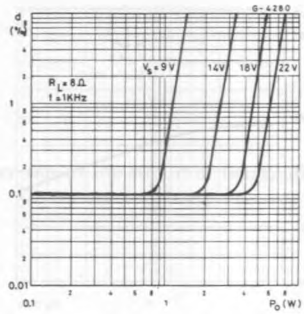


Fig. 6 - Distortion vs. output power ($R_L = 4\Omega$)

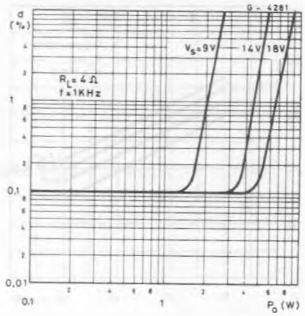


Fig. 7 - Distortion vs. frequency ($R_L = 16\Omega$)

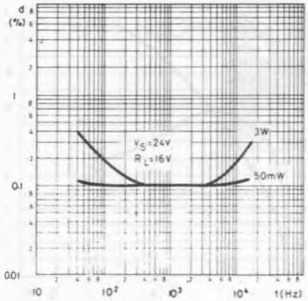


Fig. 8 - Distortion vs. frequency ($R_L = 8\Omega$)

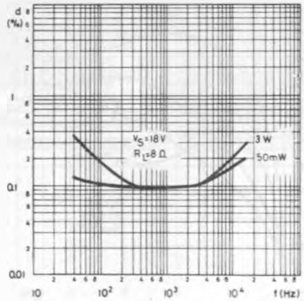


Fig. 9 - Distortion vs. frequency ($R_L = 4\Omega$)

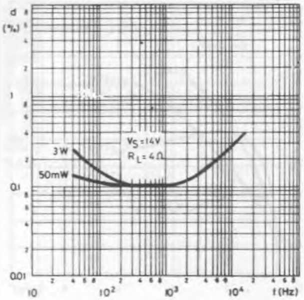


Fig. 10 - Open loop frequency response

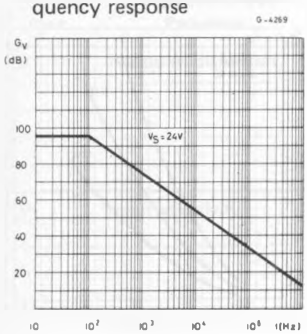


Fig. 11 - Output power vs. input voltage

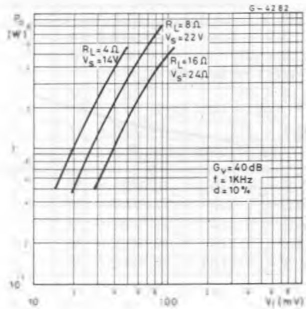


Fig. 12 - Values of capacitor C_X versus gain and B_W

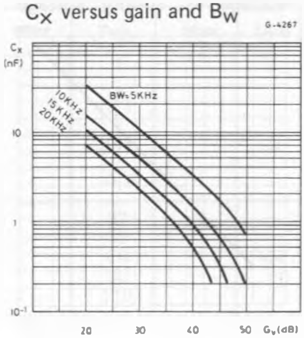


Fig. 13 - Supply voltage rejection vs. voltage gain

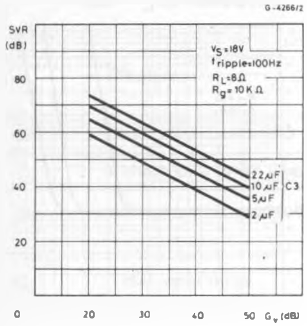


Fig. 14 - Supply voltage rejection vs. source resistance

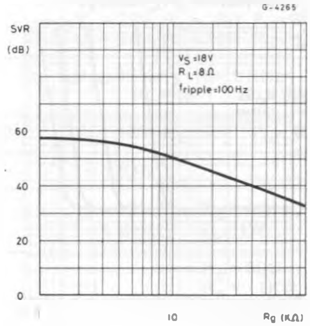


Fig. 15 - Max power dissipation vs. supply voltage

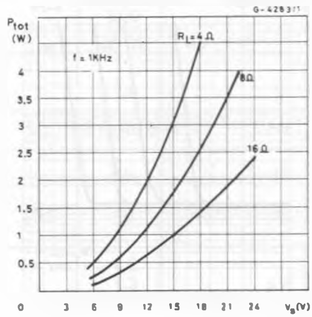


Fig. 16 - Power dissipation and efficiency vs. output power (V_s= 14V)

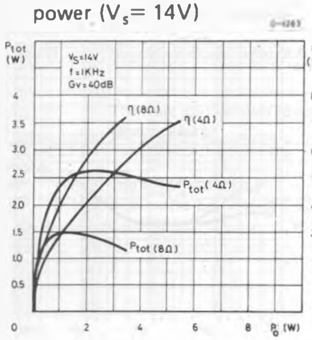


Fig. 17 - Power dissipation and efficiency vs. output power (V_s= 18V)

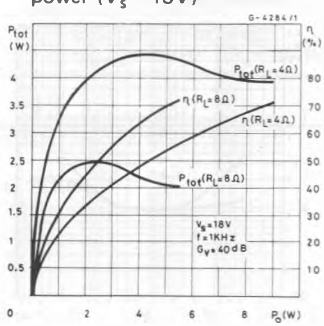
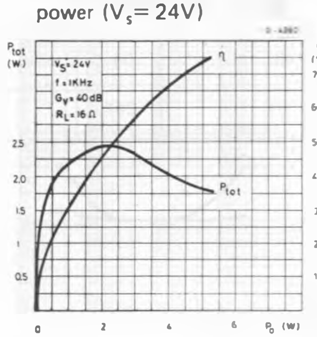
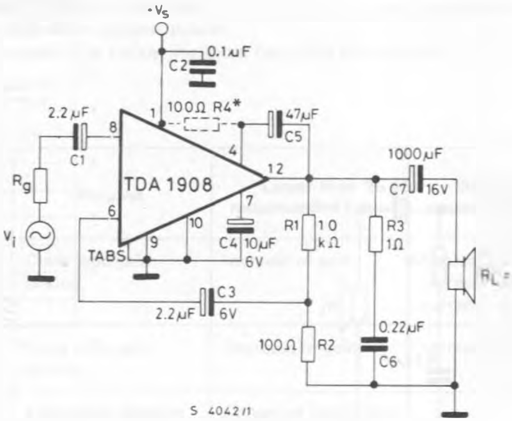


Fig. 18 - Power dissipation and efficiency vs. output power (V_s= 24V)



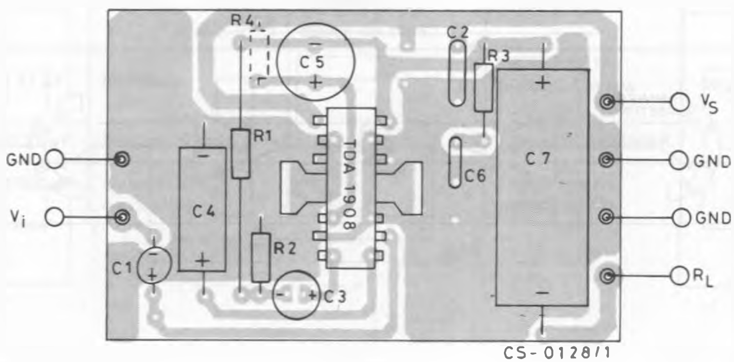
APPLICATION INFORMATION

Fig. 19 - Application circuit with bootstrap



* R4 is necessary when V_s is less than 10V.

Fig. 20 - P.C. board and component lay-out of the circuit of fig. 19 (1:1 scale)



APPLICATION INFORMATION (continued)

Fig. 21 - Application circuit without bootstrap

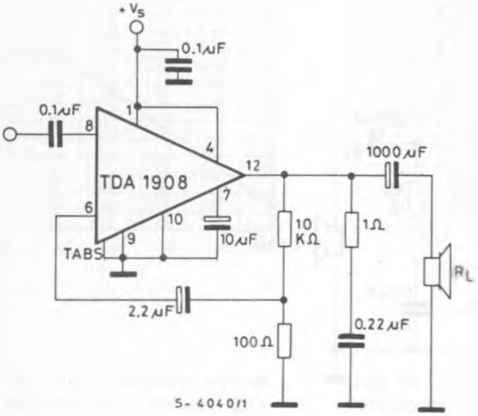


Fig. 22 - Output power vs. supply voltage (circuit of fig. 21)

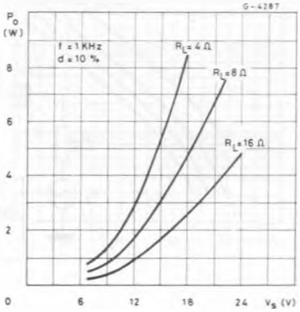
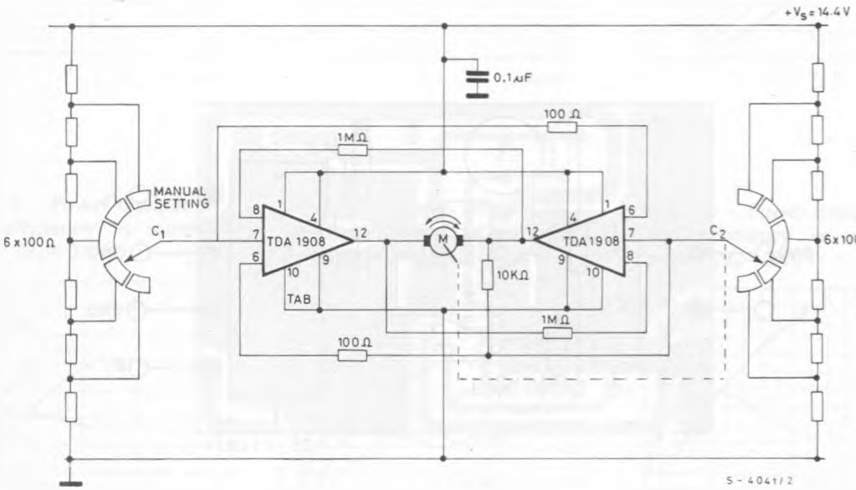


Fig. 23 - Position control for car headlights



APPLICATION SUGGESTION

The recommended values of the external components are those shown on the application circuit of fig. 19.
When the supply voltage V_s is less than 10V, a 100Ω resistor must be connected between pin 1 and pin 4 in order to obtain the maximum output power.
Different values can be used. The following table can help the designer.

Component	Raccom. value	Purpose	Larger than raccomanded value	Smaller than raccomanded value	Allowed range	
					Min.	Max.
R_1	10 KΩ	Close loop gain setting.	Increase of gain.	Decrease of gain. Increase quiescent current.	9 R_2	
R_2	100 Ω	Close loop gain setting.	Decrease of gain.	Increase of gain.		R_1/9
R_3	1 Ω	Frequency stability	Danger of oscillation at high frequencies with inductive loads.			
R_4	100 Ω	Increasing of output swing with low V_s.			47Ω	330Ω
C_1	2.2 μF	Input DC decoupling.	Lower noise	Higher low frequency cutoff. Higher noise.	0.1 μF	
C_2	0.1 μF	Supply voltage bypass.		Danger of oscillations.		
C_3	2.2 μF	Inverting input DC decoupling.	Increase of the switch-on noise	Higher low frequency cutoff.	0.1 μF	
C_4	10 μF	Ripple Rejection.	Increase of SVR. Increase of the switch-on time.	Degradation of SVR.	2.2 μF	100 μF
C_5	47 μF	Bootstrap		Increase of the distortion at low frequency	10 μF	100 μF
C_6	0.22 μF	Frequency stability.		Danger of oscillation.		
C_7	1000 μF	Output DC decoupling.		Higher low frequency cutoff.		

THERMAL SHUT-DOWN

The presence of a thermal limiting circuit offers the following advantages:

1) An overload on the output (even if it is permanent), or an above limit ambient temperature can be easily supported since the T_j cannot be higher than 150°C.

2) The heatsink can have a smaller factor of safety compared with that of a conventional circuit. There is no possibility of device damage due to high junction temperature.
If, for any reason, the junction temperature increase up to 150°C, the thermal shut-down simply reduces the power dissipation and the current consumption.

The maximum allowable power dissipation depends upon the size of the external heatsink (i.e. its thermal resistance); fig. 26 shows the dissipable power as a function of ambient temperature for different thermal resistance.

Fig. 24 - Output power and drain current vs. case temperature

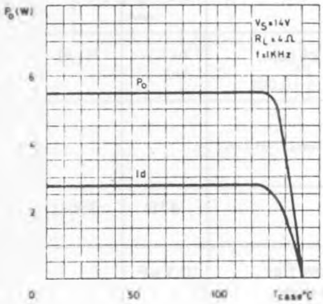


Fig. 25 - Output power and drain current vs. case temperature

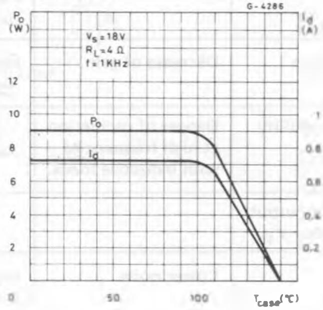
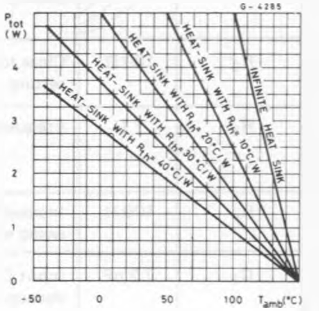


Fig. 26 - Maximum power dissipation vs. ambient temperature



MOUNTING INSTRUCTIONS

The thermal power dissipated in the circuit may be removed by soldering the tabs to a copper area on the PC board (see Fig. 27).

During soldering, tab temperature must not exceed 260°C and the soldering time must not be longer than 12 seconds.

Fig. 27 - Mounding example

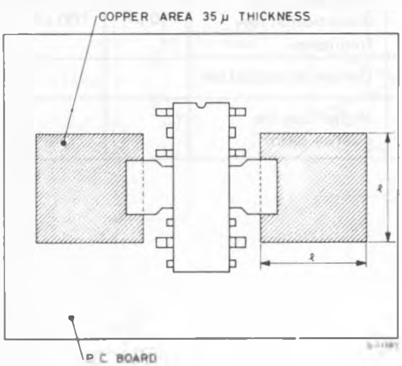


Fig. 28 - Maximum power dissipation and thermal resistance vs. side "ℓ"